

HOA1180

Reflective Sensor

FEATURES

- Choice of phototransistor or photodarlington output
- High sensitivity
- Wide operating temperature range (- 55°C to +100°C)
- 12.0 in.(305 mm) min. 28 AWG PVC insulated wire leads



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DESCRIPTION

The HOA1180 series consists of an infrared emitting diode and an NPN silicon phototransistor (HOA1180- 001, - 002) or photodarlington (HOA1180- 003), encased side- by- side on converging optical axes in a black thermoplastic housing. The detector responds to radiation from the IRED only when a reflective object passes within its field of view. The HOA1180 series employs metal can packaged components. For additional component information see SE1450, SD1440, and SD1410.

Housing material is polyester. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol.

Wire color code and functions are:

All devices
IRED anode - Red
IRED cathode - Black

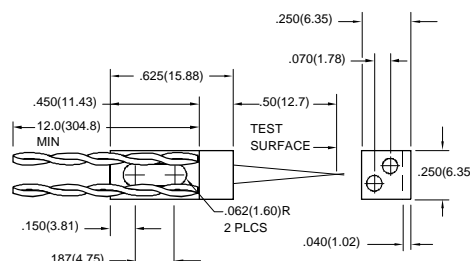
HOA1180-001
Collector - Brown
Emitter - Black

HOA1180-002
Collector - Orange
Emitter - Black

HOA1180-003
Collector - Yellow
Emitter - Black

OUTLINE DIMENSIONS in inches (mm)

Tolerance 3 plc decimals ±0.010(0.25)
2 plc decimals ±0.020(0.51)



DIM_035.dwg

HOA1180

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ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
IR EMITTER						
Forward Voltage	V_F			1.6	V	$I_F=20\text{ mA}$
Reverse Leakage Current	I_R			10	μA	$V_R=3\text{ V}$
DETECTOR						
Collector-Emitter Breakdown Voltage HOA1180-001, -002 HOA1180-003	$V_{(BR)CEO}$	30 15			V	$I_C=100\text{ }\mu\text{A}$
Emitter-Collector Breakdown Voltage	$V_{(BR)ECO}$	5.0			V	$I_E=100\text{ }\mu\text{A}$
Collector Dark Current HOA1180-001, -002 HOA1180-003	I_{CEO}			100 250	nA	$V_{CE}=10\text{ V}$ $I_F=0$
COUPLED CHARACTERISTICS						
On-State Collector Current HOA1180-001 HOA1180-002 HOA1180-003	$I_{C(ON)}$	0.04 0.16 2.0			mA	$V_{CE}=5\text{ V}$ $I_F=30\text{ mA}$ (1)
Collector-Emitter Saturation Voltage HOA1180-001 HOA1180-002 HOA1180-003	$V_{CE(SAT)}$			0.4 0.4 1.1	V	$I_F=30\text{ mA}$ (1) $I_C=5\text{ }\mu\text{A}$ $I_C=20\text{ }\mu\text{A}$ $I_C=250\text{ }\mu\text{A}$
Rise And Fall Time HOA1180-001, -002 HOA1180-003	t_r, t_f		15 75		μs	$V_{CC}=5\text{ V}, I_C=1\text{ mA}$ $R_L=1000\text{ }\Omega$ $R_L=100\text{ }\Omega$

Notes

1. Test surface is a front surface mirror (polished aluminum, 85% reflectance) located 0.50 in. (12.7 mm) from the front surface of the device.

ABSOLUTE MAXIMUM RATINGS

(25°C Free-Air Temperature unless otherwise noted)

Operating Temperature Range -55°C to 100°C

Storage Temperature Range -55°C to 125°C

Soldering Temperature (5 sec) 240°C

IR EMITTER

Power Dissipation 75 mW (1)

Reverse Voltage 3 V

Continuous Forward Current 50 mA

DETECTOR

	TRANS.	DARLINGTON
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Collector-Emitter Voltage	30 V	15 V
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Emitter-Collector Voltage	5 V	5 V
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Power Dissipation	75 mW (1)	75 mW (1)
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Collector DC Current	30 mA	30 mA
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SCHEMATIC

